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## NTE53016 thru NTE53020 Silicon Bridge Rectifier, 50A

**Features:**

- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- High Surge Current Capability
- Electrically Isolated, Low Profile Epoxy Case for Maximum Heat Dissipation
- Low Thermal Resistance
- Mounting: Through Hole with #10 Screw

**Maximum Ratings and Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified.

Single Phase, Half Wave, 60Hz, Resistive or Inductive Load, Note 1)

Maximum Recurrent Peak Reverse Voltage,  $V_{RRM}$

NTE53016 .....	200V
NTE53018 .....	600V
NTE53020 .....	1000V

Working Peak Reverse Voltage,  $V_{RWM}$

NTE53016 .....	200V
NTE53018 .....	600V
NTE53020 .....	1000V

Maximum RMS Bridge Input Voltage,  $V_{RMS}$

NTE53016 .....	140V
NTE53018 .....	420V
NTE53020 .....	700V

Maximum DC Blocking Voltage,  $V_{DC}$

NTE53016 .....	200V
NTE53018 .....	600V
NTE53020 .....	1000V

Maximum Average Forward Rectified Output Current ( $T_A = +55^\circ\text{C}$ ),  $I_{O(AV)}$  ..... 50A

Peak Forward Surge Current (8.3ms single half wave superimposed on rated load),  $I_{FSM}$  ... 500A

Maximum Forward Voltage Drop (Per element at 25A),  $V_F$  ..... 1.1V

Maximum Reverse Current at Rated DC Blocking Voltage Per Element,  $I_R$

$T_A = +25^\circ\text{C}$ .....	10 $\mu$ A
$T_A = +125^\circ\text{C}$ .....	500 $\mu$ A

$I^2t$  Rating for Fusing ( $t < 8.3\text{ms}$ ),  $I^2t$  ..... 800A<sup>2</sup>s

Typical Junction Capacitance (Note 2),  $C_j$  ..... 300pF

Typical Thermal Resistance, Junction-to-Case (Per element, Note 3),  $R_{thJC}$  ..... 1.4 $^\circ\text{C}/\text{W}$

RMS Isolation Voltage from Case to Leads,  $V_{ISO}$  ..... 2500V

Operating Temperature Range,  $T_J$  .....  $-55^\circ$  to  $+150^\circ\text{C}$

Storage Temperature Range,  $T_{stg}$  .....  $-55^\circ$  to  $+150^\circ\text{C}$

Note 1. For capacitive load, derate current by 20%.

Note 2. Measured at 1.0MHz and applied reverse voltage of 4.0VDC.

Note 3. Thermal resistance junction-to-case, mounted on a heatsink.



